TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

T C 7 M A 2 4 5 F K

Low-Voltage Octal Bus Transceiver with 3.6 V Tolerant Inputs and Outputs

The TC7MA245FK is a high performance CMOS octal bus transceiver. Designed for use in 1.8, 2.5 or 3.3 V systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

It is also designed with over voltage tolerant inputs and outputs up to 3.6 V. $\,$

The direction of data transmission is determined by the level of the DIR inputs. The \overline{OE} inputs can be used to disable the device so that the busses are effectively isolated.

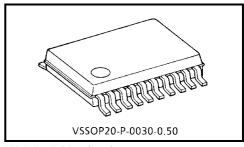
All inputs are equipped with protection circuits against static discharge.

Features

- Low voltage operation: $VCC = 1.8 \sim 3.6 V$
- High speed operation:
 - $t_{pd} = 3.5 \text{ ns} (\text{max}) (V_{CC} = 3.0 \sim 3.6 \text{ V})$ $t_{pd} = 4.2 \text{ ns} (\text{max}) (V_{CC} = 2.3 \sim 2.7 \text{ V})$ $t_{pd} = 8.4 \text{ ns} (\text{max}) (V_{CC} = 1.8 \text{ V})$
 - 3.6 V tolerant inputs and outputs.
- Package: VSSOP (US20)
- Bidirectional interface between 2.5 V and 3.3 V signals. (*1)
- Power down protection is provided on all inputs and outputs. (*2)
- Supports live insertion/withdrawal (*3)
 - *1: Do not apply a signal to any bus terminal when it is in the output mode. Damage may result.
 - *2: All floating (high impedance) bus terminal must have their input level fixed by means of pull up or pull down resistors.
 - *3: To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

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Weight: 0.03 g (typ.)

- Output current: $IOH/IOL = \pm 24 \text{ mA (min)} (VCC = 3.0 \text{ V})$ $IOH/IOL = \pm 18 \text{ mA (min)} (VCC = 2.3 \text{ V})$ $IOH/IOL = \pm 6 \text{ mA (min)} (VCC = 1.8 \text{ V})$
- Latch-up performance: ±300 mA
- ESD performance:

Machine model > $\pm 200 \text{ V}$ Human body model > $\pm 2000 \text{ V}$

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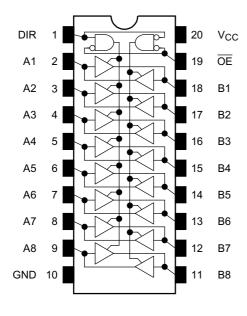
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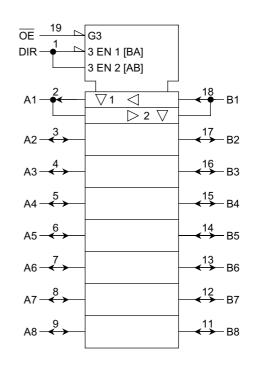
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Pin Assignment (top view)



IEC Logic Symbol



Truth Table

Inp	uts	Outputs	Fund	ction
ŌĒ	DIR	Outputs	A-Bus	B-Bus
L	L	A = B	Output	Input
L	Н	B = A	Input	Output
Н	Х	Z	Z	

X: Don't care

Z: High impedance

Maximum Ratings

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	-0.5~4.6	V	
DC input voltage (DIR, OE)	V _{IN}	-0.5~4.6	V	
DC bus I/O voltage	V _{I/O}	-0.5~4.6 (Note1)	V	
De bus i/o voltage	VI/O	-0.5~V _{CC} + 0.5 (Note2)		
Input diode current	I _{IK}	-50	mA	
Output diode current	I _{OK}	±50 (Note3)	mA	
DC output current	IOUT	±50	mA	
Power dissipation	PD	180	mW	
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA	
Storage temperature	T _{stg}	-65~150	°C	

Note1: Off-state

Note2: High or low state. IOUT absolute maximum rating must be observed.

Note3: V_{OUT} < GND, V_{OUT} > V_{CC}

Recommended Operating Range

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	1.8~3.6	V
Supply Voltage	VCC	1.2~3.6 (Note4)	v
Input voltage (DIR, OE)	V _{IN}	-0.3~3.6	V
Bus I/O voltage	V _{I/O}	0~3.6 (Note5)	V
Bus i/O voltage	VI/O	0~V _{CC} (Note6)	v
		±24 (Note7)	
Output current	I _{OH} /I _{OL}	±18 (Note8)	mA
		±6 (Note9)	
Operating temperature	T _{opr}	-40~85	°C
Input rise and fall time	dt/dv	0~10 (Note10)	ns/V

Note4: Data retention only

Note5: Off-state

Note6: High or low state

Note7: V_{CC} = 3.0~3.6 V

Note8: V_{CC} = 2.3~2.7 V

Note9: $V_{CC} = 1.8 V$

Note10: $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$

Electrical Characteristics

DC Characteristics (Ta = –40~85°C, 2.7 V < V_{CC} \leq 3.6 V)

Characteristics		Symbol	Test Condition			Min	Max	Unit
Characte	Characteristics Symbol Test Condition		V _{CC} (V)	IVIIII	IVIAA	Onic		
Input voltage	High level	VIH		—	2.7~3.6	2.0	_	V
input voltage	Low level	VIL		—	2.7~3.6	_	0.8	v
				I _{OH} = -100 μA	2.7~3.6	V _{CC} - 0.2	_	
	High level	VoH	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_	
				$I_{OH} = -18 \text{ mA}$	3.0	2.4	—	
Output voltage			I _{OH} = -24 mA	3.0	2.2	_	v	
			$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 100 \ \mu A$	2.7~3.6	_	0.2	
	Low level	Vol		$I_{OL} = 12 \text{ mA}$	2.7	_	0.4	
	LOW IEVEI	VOL		I _{OL} = 18 mA	3.0	_	0.4	
				I _{OL} = 24 mA	3.0		0.55	
Input leakage curr	ent	I _{IN}	V _{IN} = 0~3.6 V		2.7~3.6	_	±5.0	μA
3-state output off-state current		I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0~3.6 \text{ V}$		2.7~3.6	_	±10.0	μA
Power off leakage	current	IOFF	V _{IN} , V _{OUT} = 0~3.6 V		0	_	10.0	μA
Quiescent supply current			$V_{IN} = V_{CC}$ or GND		2.7~3.6	_	20.0	
		Icc	$V_{CC} \stackrel{\scriptstyle \leq}{=} (V_{IN},V_{OUT}) \stackrel{\scriptstyle \leq}{=}$	3.6 V	2.7~3.6	_	±20.0	μA
Increase in I _{CC} pe	er input	∆l _{CC}	$V_{IH} = V_{CC} - 0.6 V$		2.7~3.6	_	750	

DC Characteristics (Ta = -40~85°C, 2.3 V \leq V_{CC} \leq 2.7 V)

Character	istics	Symbol	Tes	Test Condition		Test Condition		Min	Max	Unit
Innut voltogo	High level	VIH		_	2.3~2.7	1.6	—	V		
Input voltage	Low level	VIL		_	2.3~2.7		0.7	v		
				I _{OH} = -100 μA	2.3~2.7	V _{CC} - 0.2	_			
	High level	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -6 \text{ mA}$	2.3	2.0	_			
	-			$I_{OH} = -12 \text{ mA}$	2.3	1.8	_	V		
Output voltage				I _{OH} = -18 mA	2.3	1.7	_			
			$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 100 \ \mu A$	2.3~2.7	_	0.2			
	Low level	V _{OL}		$V_{IN} = V_{IH} \text{ or } V_{IL}$	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 12 \text{ mA}$	2.3	_	0.4	
				I _{OL} = 18 mA	2.3	_	0.6			
Input leakage curre	ent	I _{IN}	V _{IN} = 0~3.6 V		2.3~2.7	_	±5.0	μA		
2 atoto output off a	tata aurrant	1	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$V_{IN} = V_{IH}$ or V_{IL}			±10.0			
S-State Output on-S	state output off-state current I _{OZ}		V _{OUT} = 0~3.6 V		2.3~2.7		±10.0	μA		
Power off leakage	current	I _{OFF}	V _{IN} , V _{OUT} = 0~3.6 V		0	—	10.0	μA		
Quiescent supply of			$V_{IN} = V_{CC}$ or GND	$V_{IN} = V_{CC}$ or GND		—	20.0	μA		
Quiescent supply (Icc	$V_{CC} \leq (V_{IN}, V_{OUT}) \leq 1$	$V_{CC} \leq (V_{IN}, V_{OUT}) \leq 3.6 \text{ V}$		_	±20.0	μA		

DC Characteristics (Ta = -40~85°C, 1.8 V \leq V_{CC} < 2.3 V)

Characteristics		Symbol	ol Test Condition			Min	Max	Unit										
Characteria	51105	Symbol	1631	Condition	$V_{CC}(V)$	IVIIII	Μαλ	Onit										
Input voltage	High level	VIH		_	1.8~2.3	$0.7 \times V_{CC}$	_	V										
mput voltage	Low level	V _{IL}		_	1.8~2.3		$0.2 \times V_{CC}$	v										
	High level	Vон	VIN = VIH or VIL	I _{OH} = -100 μA	1.8	V _{CC} - 0.2	_											
Output voltage				I _{OH} = -6 mA	1.8	1.4		V										
	Low level	V _{OL}	VIN = VIH or VII	I _{OL} = 100 μA	1.8	_	0.2											
	LOWIEVEI	VOL	VIN – VIH OL VIL	$I_{OL} = 6 \text{ mA}$	1.8		0.3											
Input leakage curren	nt	I _{IN}	V _{IN} = 0~3.6 V		1.8		±5.0	μA										
3-state output off-sta	state output off-state current I_{OZ} $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = 0 \sim 3.6 \text{ V}$		1.8		±10.0	μΑ												
Power off leakage c	urrent	I _{OFF}	$V_{IN}, V_{OUT} = 0 \sim 3.6 V$		V _{IN} , V _{OUT} = 0~3.6 V		V _{IN} , V _{OUT} = 0~3.6 V		V _{IN} , V _{OUT} = 0~3.6 V		V _{IN} , V _{OUT} = 0~3.6 V		$V_{\text{IN}}, V_{\text{OUT}} = 0 \sim 3.6 \text{ V}$		0	_	10.0	μA
Quiescent supply cu	urrent	Icc	$V_{IN} = V_{CC}$ or GND		1.8		20.0	μA										
Quiescent supply ct		100	$V_{CC} \leq (V_{IN}, V_{OUT}) \leq 3.6 \text{ V}$		1.8	_	±20.0	μA										

AC Characteristics (Ta = -40~85°C, Input: $t_r = t_f = 2.0 \text{ ns}$, $C_L = 30 \text{ pF}$, $R_L = 500 \Omega$)

Characteristics	Symbol	Symbol Test Condition		Min	Мах	Unit
	-,		$V_{CC}(V)$		max	Onic
	+		1.8	1.5	8.4	
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.5 ± 0.2	0.8	4.2	ns
	t _{pHL}		3.3 ± 0.3	0.6	3.5	
	+		1.8	1.5	9.8	
3-state output enable time	t _{pZL} t _{pZH}	Figure 1, Figure 3	2.5 ± 0.2	0.8	5.6	ns
			3.3 ± 0.3	0.6	4.5	
	t . –			1.5	7.2	
3-state output disable time	t _{pLZ} t _{pHZ}	Figure 1, Figure 3	2.5 ± 0.2	0.8	4.0	ns
			3.3 ± 0.3	0.6	3.6	
	4		1.8		0.5	
Output to output skew	t _{osLH}	(Note11)	2.5 ± 0.2		0.5	ns
	t _{osHL}		3.3 ± 0.3		0.5	

For $C_L = 50$ pF, add approximately 300 ps to the AC maximum specification.

Note11: This parameter is guaranteed by design.

 $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$

Dynamic Switching Characteristics (Ta = 25°C, Input: $t_r = t_f = 2.0 \text{ ns}, C_L = 30 \text{ pF}$)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Тур.	Unit
		$V_{IH} = 1.8 V, V_{IL} = 0 V$	(Note12)	1.8	0.25	
Quiet output maximum dynamic V_{OL}	V _{OLP}	$V_{IH} = 2.5 V, V_{IL} = 0 V$	(Note12)	2.5	0.6	V
		$V_{IH} = 3.3 V, V_{IL} = 0 V$	(Note12)	3.3	0.8	
		$V_{IH} = 1.8 V, V_{IL} = 0 V$	(Note12)	1.8	-0.25	
Quiet output minimum dynamic V_{OL}	V _{OLV}	$V_{IH} = 2.5 V, V_{IL} = 0 V$	(Note12)	2.5	-0.6	V
		$V_{IH} = 3.3 V, V_{IL} = 0 V$	(Note12)	3.3	-0.8	
		$V_{IH} = 1.8 V, V_{IL} = 0 V$	(Note12)	1.8	1.5	
Quiet output minimum dynamic V_{OH}	V _{OHV}	$V_{IH} = 2.5 V, V_{IL} = 0 V$	(Note12)	2.5	1.9	V
		$V_{IH} = 3.3 V, V_{IL} = 0 V$	(Note12)	3.3	2.2	

Note12: This parameter is guaranteed by design.

Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition		Тур.	Unit
Characteristics	Symbol Test Condition		V _{CC} (V)	тур.	Unit
Input capacitance	C _{IN}	_	1.8, 2.5, 3.3	6	pF
Bus I/O capacitance	C _{I/O}	_	1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz (Note13	1.8, 2.5, 3.3	20	pF

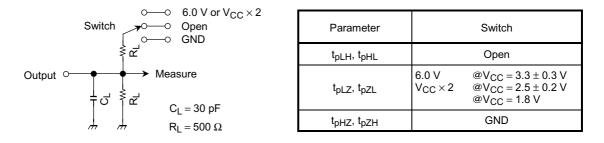
Note13: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$

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AC Test Circuit





AC Waveform

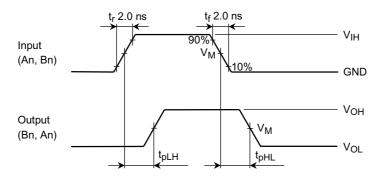


Figure 2 t_{pLH}, t_{pHL}

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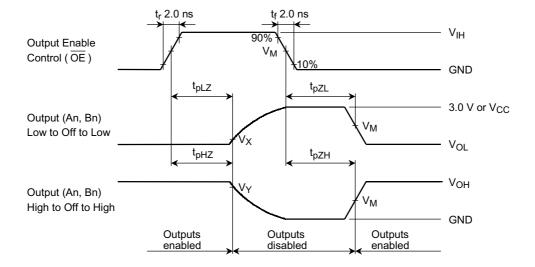


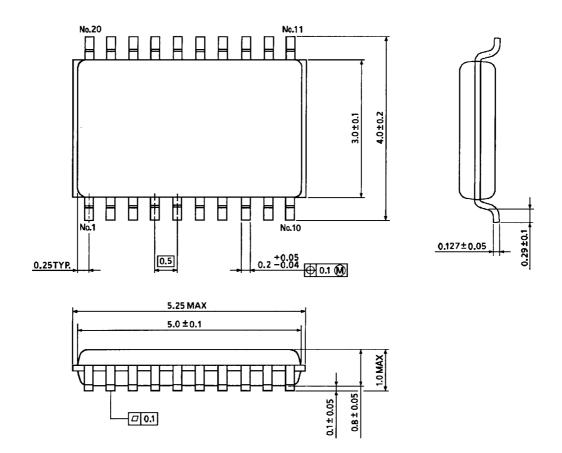
Figure 3	t _{pLZ} , t	pHZ, t	φ ZL ,	t _{pZH}
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Symbol	Vcc						
Symbol	$3.3\pm0.3~\text{V}$	$2.5\pm0.2~\text{V}$	1.8 V				
VIH	2.7 V	V _{CC}	V _{CC}				
VM	1.5 V	V _{CC} /2	V _{CC} /2				
Vx	V _{OL} + 0.3 V	V _{OL} + 0.15 V	V _{OL} + 0.15 V				
VY	V _{OH} – 0.3 V	V _{OH} – 0.15 V	V _{OH} – 0.15 V				

Package Dimensions

VSSOP20-P-0030-0.50

Unit : mm



Weight: 0.03 g (typ.)